

### FEATURES

- Very Low Noise  $5 \text{ nV}/\sqrt{\text{Hz}}$  @ 1 kHz Max
- Excellent Input Offset Voltage  $75 \text{ }\mu\text{V}$  Max
- Low Offset Voltage Drift  $1 \text{ }\mu\text{V}/^\circ\text{C}$  Max
- Very High Gain  $1500 \text{ V/mV}$  Min
- Outstanding CMR  $106 \text{ dB}$  Min
- Slew Rate  $2.4 \text{ V}/\mu\text{s}$  Typ
- Gain Bandwidth Product  $5 \text{ MHz}$  Typ
- Industry-Standard 8-Lead Dual Pinout

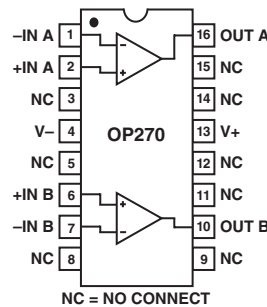
### GENERAL DESCRIPTION

The OP270 is a high performance, monolithic, dual operational amplifier with exceptionally low voltage noise,  $5 \text{ nV}/\sqrt{\text{Hz}}$  max at 1 kHz. It offers comparable performance to ADI's industry standard OP27.

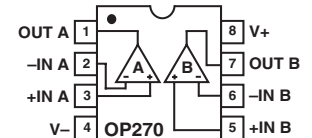
The OP270 features an input offset voltage below  $75 \text{ }\mu\text{V}$  and an offset drift under  $1 \text{ }\mu\text{V}/^\circ\text{C}$ , guaranteed over the full military temperature range. Open-loop gain of the OP270 is over 1,500,000 into a  $10 \text{ k}\Omega$  load, ensuring excellent gain accuracy and linearity, even in high gain applications. Input bias current is under  $20 \text{ nA}$ , which reduces errors due to signal source resistance. The OP270's CMR of over  $106 \text{ dB}$  and PSRR of less than  $3.2 \text{ }\mu\text{V/V}$  significantly reduce errors due to ground noise and power supply fluctuations. Power consumption of the dual OP270 is one-third less than two OP27s, a significant advantage for power conscious applications. The OP270 is unity-gain stable with a gain bandwidth product of  $5 \text{ MHz}$  and a slew rate of  $2.4 \text{ V}/\mu\text{s}$ .

### CONNECTION DIAGRAMS

16-Lead SOIC  
(S-Suffix)



8-Lead PDIP (P-Suffix)  
8-Lead Cerdip  
(Z-Suffix)



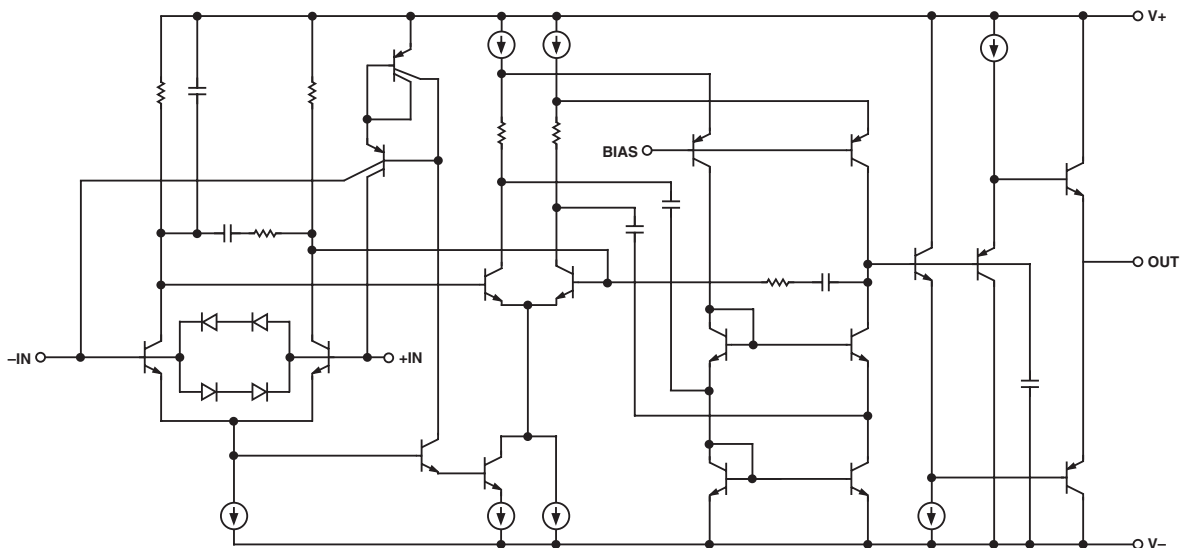
The OP270 offers excellent amplifier matching, which is important for applications such as multiple gain blocks, low noise instrumentation amplifiers, dual buffers, and low noise active filters.

The OP270 conforms to the industry-standard 8-lead DIP pinout. It is pin compatible with the MC1458, SE5532/A, RM4558, and HA5102 dual op amps, and can be used to upgrade systems using those devices.

For higher speed applications, the OP271, with a slew rate of  $8 \text{ V}/\mu\text{s}$ , is recommended. For a quad op amp, see the OP470.

### SIMPLIFIED SCHEMATIC

(One of Two Amplifiers Is Shown)



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# OP270—SPECIFICATIONS ( $V_S = \pm 15\text{ V}$ , $T_A = 25^\circ\text{C}$ , unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	OP270E			OP270F			OP270G			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
Input Offset Voltage	$V_{OS}$		10	75		20	150		50	250	$\mu\text{V}$	
Input Offset Current	$I_{OS}$	$V_{CM} = 0\text{ V}$	1	10		3	15		5	20	nA	
Input Bias Current	$I_B$	$V_{CM} = 0\text{ V}$	5	20		10	40		15	60	nA	
Input Noise Voltage	$e_n$ p-p	0.1 Hz to 10 Hz (Note 1)	80	200		80	200		80		nV p-p	
Input Noise Voltage Density	$e_n$	$f_o = 10\text{ Hz}$	3.6	6.5		3.6	6.5		3.6		$\text{nV}/\sqrt{\text{Hz}}$	
		$f_o = 100\text{ Hz}$	3.2	5.5		3.2	5.5		3.2		$\text{nV}/\sqrt{\text{Hz}}$	
		$f_o = 1\text{ kHz}$ (Note 2)	3.2	5.0		3.2	5.0		3.2		$\text{nV}/\sqrt{\text{Hz}}$	
Input Noise Current Density	$i_n$	$f_o = 10\text{ Hz}$	1.1			1.1			1.1		$\text{pA}/\sqrt{\text{Hz}}$	
		$f_o = 100\text{ Hz}$	0.7			0.7			0.7		$\text{pA}/\sqrt{\text{Hz}}$	
		$f_o = 1\text{ kHz}$	0.6			0.6			0.6		$\text{pA}/\sqrt{\text{Hz}}$	
Large-Signal Voltage Gain	$A_{VO}$	$V_O = \pm 10\text{ V}$ $R_L = 10\text{ k}\Omega$	1500	2300		1000	1700		750	1500	V/mV	
		$R_L = 2\text{ k}\Omega$	750	1200		500	900		350	700	V/mV	
Input Voltage Range	IVR	(Note 3)	$\pm 12$	$\pm 12.5$		$\pm 12$	$\pm 12.5$		$\pm 12$	$\pm 12.5$	V	
Output Voltage Swing Common-Mode Rejection	$V_O$ CMR	$R_L \geq 2\text{ k}\Omega$ $V_{CM} = \pm 11\text{ V}$	$\pm 12$	$\pm 13.5$		$\pm 12$	$\pm 13.5$		$\pm 12$	$\pm 13.5$	V dB	
Power Supply Rejection Ratio	PSRR	$V_S = \pm 4.5\text{ V}$ to $\pm 18\text{ V}$		0.56 3.2		1.0	5.6		1.5	6	$\mu\text{V}/\text{V}$	
Slew Rate	SR		1.7	2.4		1.7	2.4		1.7	2.4	$\text{V}/\mu\text{s}$	
Supply Current (All Amplifiers)	$I_{SY}$	No Load	4	6.5		4	6.5		4	6.5	mA	
Gain Bandwidth Product	GBP		5			5			5		MHz	
Channel Separation	CS	$V_O = \pm 20\text{ V p-p}$ $f_o = 10\text{ Hz}$ (Note 1)	125	175		125	175		175		dB	
Input Capacitance	$C_{IN}$		3			3			3		pF	
Input Resistance Differential-Mode	$R_{IN}$		0.4			0.4			0.4		$\text{M}\Omega$	
Input Resistance Common-Mode	$R_{INCM}$		20			20			20		$\text{G}\Omega$	
Settling Time	$t_S$	$A_V = +1$ , 10 V Step to 0.01%	5			5			5		$\mu\text{s}$	

## NOTES

1. Guaranteed but not 100% tested.
2. Sample tested.
3. Guaranteed by CMR test.

Specifications subject to change without notice.

# SPECIFICATIONS

## ELECTRICAL SPECIFICATIONS ( $V_S = \pm 15\text{ V}$ , $-40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$ , unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	OP270E			OP270F			OP270G			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
Input Offset Voltage Average Input	$V_{OS}$		25	150		45	275		100	400	$\mu\text{V}$	
Offset Voltage Drift	$TCV_{OS}$		0.2	1		0.4	2		0.7	3	$\mu\text{V}/^\circ\text{C}$	
Input Offset Current	$I_{OS}$	$V_{CM} = 0\text{ V}$	1.5	30		5	40		15	50	nA	
Input Bias Voltage	$I_B$	$V_{CM} = 0\text{ V}$	6	60		15	70		19	80	nA	
Large-Signal Voltage Gain	$A_{VO}$	$V_O = \pm 10\text{ V}$ $R_L = 10\text{ k}\Omega$ $R_L = 2\text{ k}\Omega$	1000 500	1800 900		600 300	1400 700		400 225	1250 670	V/mV V/mV	
Input Voltage Range*	IVR		$\pm 12$	$\pm 12.5$		$\pm 12$	$\pm 12.5$		$\pm 12$	$\pm 12.5$	V	
Output Voltage Swing Common-Mode Rejection	$V_O$ CMR	$R_L \geq 2\text{ k}\Omega$ $V_{CM} = \pm 11\text{ V}$	$\pm 12$	$\pm 13.5$		$\pm 12$	$\pm 13.5$		$\pm 12$	$\pm 13.5$	V dB	
Power Supply Rejection Ratio	PSRR	$V_S = \pm 4.5\text{ V}$ to $\pm 18\text{ V}$	0.7	5.6		1.8	10		2.0	1.5	$\mu\text{V}/\text{V}$	
Supply Current (All Amplifiers)	$I_{SY}$	No Load	4.4	7.2		4.4	7.2		4.4	7.2	mA	

\* Guaranteed by CMR test.

Specifications subject to change without notice.

# OP270

## ABSOLUTE MAXIMUM RATINGS<sup>1</sup>

Supply Voltage	±18 V
Differential Input Voltage <sup>2</sup>	±1.0 V
Differential Input Current <sup>2</sup>	±25 mA
Input Voltage	Supply Voltage
Output Short-Circuit Duration	Continuous
Storage Temperature Range	
P, S, Z Package	-65°C to +150°C
Lead Temperature Range (Soldering, 60 sec)	300°C
Junction Temperature (T <sub>J</sub> )	-65°C to +150°C

## Operating Temperature Range

OP270E, OP270F, OP270G	-40°C to +85°C
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## NOTES

<sup>1</sup> Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those listed in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

<sup>2</sup> The OP270's inputs are protected by back-to-back diodes. Current limiting resistors are not used, in order to achieve low noise performance. If differential voltage exceeds +10 V, the input current should be limited to ±25 mA.

## ORDERING GUIDE

Model	T <sub>A</sub> = +25°C V <sub>OS</sub> Max (μV)	θ <sub>JC</sub> (°C/W)	θ <sub>JA</sub> * (°C/W)	Temperature Range	Package Description	Package Option
OP270EZ	75	12	134	XIND	8-Lead CERDIP	Q-8 (Z-Suffix)
OP270FZ	150	12	134	XIND	8-Lead CERDIP	Q-8 (Z-Suffix)
OP270GP	250	37	96	XIND	8-Lead PDIP	N-8 (P-Suffix)
OP270GS	250	27	92	XIND	16-Lead SOIC	RW-16 (S-Suffix)

\*θ<sub>JA</sub> is specified for worst-case mounting conditions, i.e., θ<sub>JA</sub> is specified for device in socket for CERDIP and PDIP packages; θ<sub>JA</sub> is specified for device soldered to printed circuit board for SOIC package.

For military processed devices, please refer to the Standard Microcircuit Drawing (SMD) available at [www.dsccl.dla.mil/programs/milspec/default.asp](http://www.dsccl.dla.mil/programs/milspec/default.asp).

SMD Part Number	ADI Equivalent
5962-8872101PA	OP270AZMDA

## CAUTION

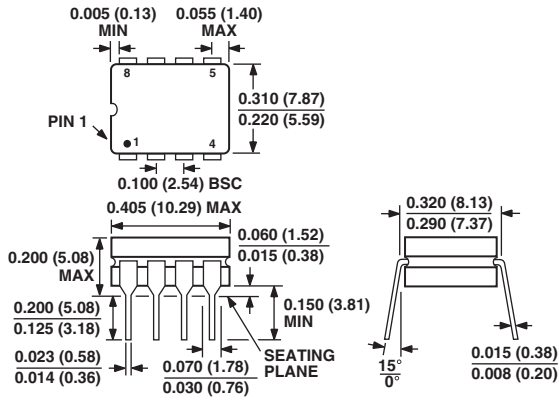
ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the OP270 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



OUTLINE DIMENSIONS

8-Lead Ceramic Dual In-Line Package [CERDIP]  
Z-Suffix  
(Q-8)

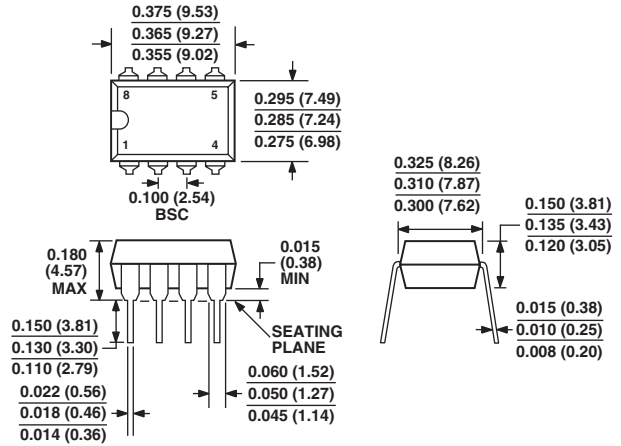
Dimensions shown in inches and (millimeters)



CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETERS DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN

8-Lead Plastic Dual In-Line Package [PDIP]  
P-Suffix  
(N-8)

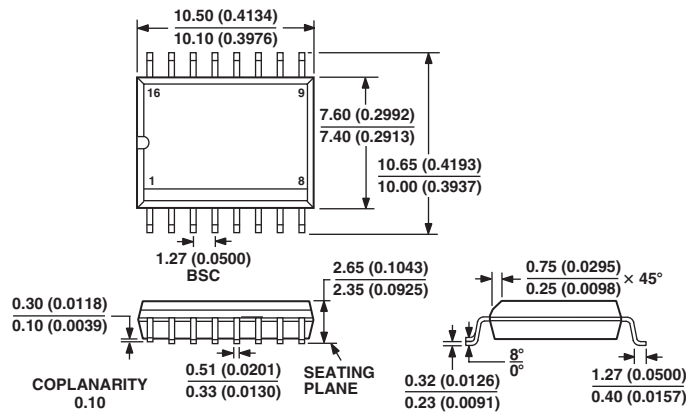
Dimensions shown in inches and (millimeters)



COMPLIANT TO JEDEC STANDARDS MO-095AA  
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16-Lead Standard Small Outline Package [SOIC]  
Wide Body  
S-Suffix  
(RW-16)

Dimensions shown in millimeters and (inches)



COMPLIANT TO JEDEC STANDARDS MS-013AA  
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN